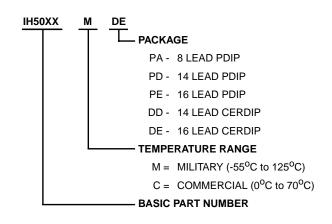


Part Number Information

PART NUMBER	CHANNELS	LOGIC LEVEL	PACKAGE	PKG NO.
IH5009	4	+15	DD, PD	
IH5010	4	+5	DD, PD	
IH5011	4	+15	DE, PE	
IH5012	4	+5	DE, PE	
IH5014	3	+5	DD, PD	
IH5016	3	+5	DE, PE	
IH5017	2	+15	PA	
IH5018	2	+5	DD, PA	
IH5019	2	+15	DE, PA	
IH5020	2	+5	DE, PA	
IH5022	1	+5	DD, PA	
IH5024	1	+5	PA	

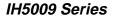
NOTE: Mil-Temperature range (-55°C to 125°C) available in ceramic packages only.

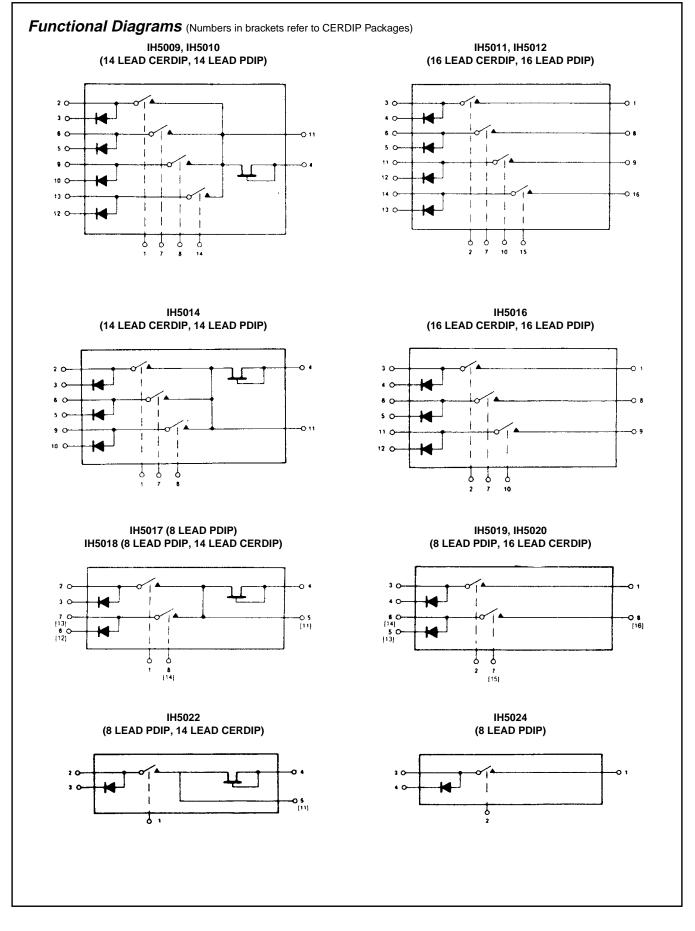


SPST switch action is obtained by leaving the diode cathode unconnected; for SPDT action, the cathode should be grounded (0V). The parts are intended for high performance multiplexing and commutating usage. A logic "0" turns the

channel ON and a logic "1" turns the channel OFF.

CAUTION: These devices are sensitive to electrostatic discharge. Users should follow proper IC Handling Procedures. Copyright © Harris Corporation 1999





Absolute Maximum Ratings

Positive Analog Signal Voltage
Negative Analog Signal Voltage15V
Diode Current
Power Dissipation (Note) 500mW

Thermal Information

Maximum Storage Temperature Range $\ldots \ldots \ldots -65^oC$ to 150^oC Maximum Lead Temperature (Soldering 10s) $\ldots \ldots \ldots 300^oC$

Operating Conditions

Temperature Range

5009C Series	•	0 ^o C to 70 ^o C

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE: Dissipation rating assumes device is mounted with all leads welded or soldered to printed circuit board in ambient temperature below 75°C. For higher temperature, derate at rate of 5m/W°C.

PARAMETER	(NOTE 1) SYMBOL	(NOTE 4) TEST CONDITIONS	(NOTE 2) TYPE	-55 ^o C (M) 0 ^o C (C) MIN/MAX	25 ⁰ C		125 ^o C(M)	
					ТҮР	MIN/MAX	70°C (C) MIN/MAX	UNITS
Input Current-ON	I _{IN(ON)}	ALL	$V_{IN} = 0V, I_D = 2mA$	-	0.01	±0.5	100	μΑ
Input Current-OFF	IN(OFF)	5V Logic Ckts	$V_{IN} = +4.5V,$ $V_A = \pm 10V$	-	0.04	±0.5	20	nA
Input Current-OFF	IN(OFF)	15V Logic Ckts	$V_{IN} = +11V,$ $V_A = \pm 10V$	-	0.04	±0.5	20	nA
Channel Control Voltage-ON	V _{IN(ON)}	5V Logic Ckts	Note 3	0.5	-	0.5	0.5	V
Channel Control Voltage-ON	V _{IN(ON)}	15V Logic Ckts	Note 3	1.5	-	1.5	1.5	V
Channel Control Voltage-OFF	V _{IN(OFF)}	5V Logic Ckts	Note 3	-	-	4.5	4.5	V
Channel Control Voltage-OFF	V _{IN(OFF)}	15V Logic Ckts	Note 3	-	-	11.0	11.0	V
Leakage Current-OFF	I _{D(OFF)}	5V Logic Ckts	$V_{IN} = +4.5V,$ $V_A = \pm 10V$	-	0.02	±0.5	20	nA
Leakage Current-OFF	I _{D(OFF)}	15V Logic Ckts	$V_{IN} = +11V,$ $V_A = \pm 10V$	-	0.02	±0.5	20	nA
Leakage Current-ON	I _{D(ON)}	5V Logic Ckts	V _{IN} = 0V, I _S = 1mA	-	0.30	±1.0	1000 (M) 200 (C)	nA
Leakage Current-ON	I _{D(ON)}	15V Logic Ckts	V _{IN} = 0V, I _S = 1mA	-	0.10	±0.5	500 (M) 100 (C)	nA
Leakage Current-ON	I _{D(ON)}	5V Logic Ckts	$V_{IN} = 0V, I_S = 2mA$	-	-	1.0	10	μΑ
Leakage Current-ON	I _{D(ON)}	15V Logic Ckts	$V_{IN} = 0V, I_S = 2mA$	-	-	2.0	100	μA
Drain-Source ON-Resistance	^r DS(ON)	5V Logic Ckts	I _D = 2mA, V _{IN} = 0.5V	150	90	150	385 (M) 240 (C)	Ω
Drain-Source ON-Resistance	^r DS(ON)	15V Logic Ckts	I _D = 2mA, V _{IN} = 1.5V	100	80	100	250 (M) 160 (C)	Ω
Turn-ON Time	t _(ON)	All		-	150	500	-	ns
Turn-OFF Time	^t (OFF)	All		-	300	500	-	ns
Cross Talk	СТ	All	f = 100Hz	-	120	-	-	dB

NOTES:

1. (OFF) and (ON) subscript notation refers to the conduction state of the FET switch for the given test.

2. Refer to Figure 1 for definition of terms.

3. VIN(ON) and VIN(OFF) are test conditions guaranteed by the tests of rDS(ON) and ID(OFF) respectively.

4. "5V Logic CKTS" applies to even-numbered devices. "15V Logic CKTS" applies to odd-numbered devices.